Electronic Supplementary Information

High Efficiency Hybrid White Organic Light-Emitting Diodes based on a Simple and Efficient Exciton Regulation Emissive Layer

Structure

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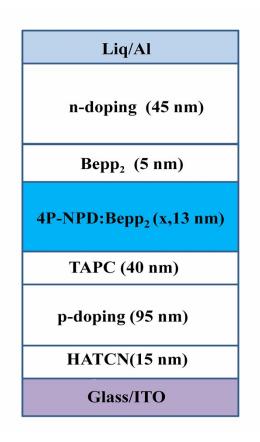


Figure S1.Schematic structure of designed Blue OLED

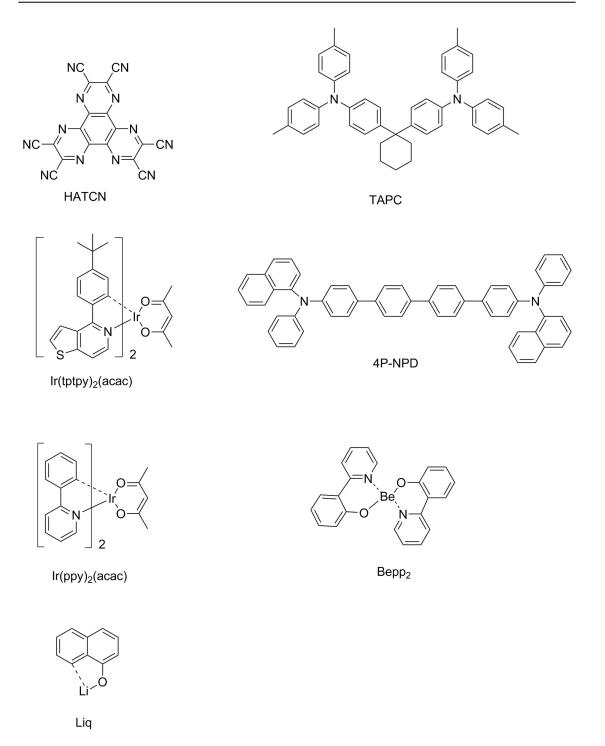


Figure S2. The molecular structures of organic materials used for OLED in this work.

W1 structure: ITO/HAT-CN (15 nm)/TAPC: HAT-CN (4/2, 95 nm)/TAPC (40 nm)/4P-NPD: Ir(tptpy)₂(acac) (4%, 5 nm)/4P-NPD: Bepp₂ (1: 1, 13 nm)/Bepp₂ (2 nm)/Ir(ppy)₂(acac) (0.4 nm)/Bepp₂ (3 nm)/Bepp₂: Liq (4.5%, 50 nm)/Liq (1.25 nm)/Al,

W2 structure: ITO/HAT-CN (15 nm)/TAPC: HAT-CN (4/2, 95 nm)/TAPC (40 nm)/4P-NPD: Ir(tptpy)₂(acac) (4%, 5 nm)/4P-NPD: Bepp₂ (2: 1, 13 nm)/Bepp₂ (5nm)/Bepp₂: Liq (4.5%, 50 nm)/Liq (1.25 nm)/AI.

W6 structure: ITO/HATCN (15 nm)/TAPC: HATCN (4/2, 95 nm)/TAPC (40 nm)/4P-NPD: Ir(tptpy)₂(acac) (4%, 5 nm)/4P-NPD: Bepp₂ (2: 1, 13 nm)/Bepp₂ (2 nm)/Ir(ppy)₂(acac) (0.4 nm)/Bepp₂ (3 nm)/Bepp₂: Liq (4.5%, 50 nm)/Liq (1.25 nm)/AI.

Device	$V_{on}^{a}(V)$	Max/@100 cd m ⁻² /@1000 cd m ⁻²			- CRI ^b	$CIE^{b}(x,y)$
		CE (cd A ⁻¹)	PE (lm W ⁻¹)	EQE (%)		$CIE^{\circ}(X,Y)$
W1	2.6	58.3/56.7/48.7	65.5/59.3/44.9	16.7/13.5/11.0	42	(0.43,0.52)
W2	2.6	47.3/34.5/18.2	57.2/33.9/13.5	15.8/12.1/13.5	51	(0.36,0.37)
W6	2.6	60.3/40.8/28.3	72.9/37.7/20.2	18.2/12.5/8.8	46	(0.40,0.49)

Table S1 Summary of EL performances of the resulting WOLEDs.

^a Turn-on voltage estimated at a brightness of >1cd m⁻². ^b Emission peak and the corresponding CRI and CIE coordinates obtained at a voltage of 4 V.

Table S1. Summary of EL performances of the resulting WOLEDs.